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# Electronegative diversity induced localized built-in electric field in a single phased $MoS_xSe_yN_z$ for selectivity-enhanced visible photocatalytic $CO_2$ reduction

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#### ABSTRACT

How to passivate the recombination in a photocatalyst is a big challenge to achieve efficient photocatalytic  $CO_2$  reduction. Besides the heterojunction strategy, the design of intrinsic built-in electric field in a single phased photocatalyst can facilitate the transport while it does not introduce extra side reactions induced by the unbalanced photocarriers. This work utilizes the electronegative diversity between chalcogens and non-chalcogen element in a quarternary transition metal dichalcogenide of  $MoS_xSe_yN_z$  to define localized built-in electric fields. It has been revealed that the nitrogen induced intrinsic dipole moments and potential energy have strengthened the built-in electric fields, promoting the separation of photocarriers and the gathering of electrons around N sites, which has been found to improve the adsorption of intermediate products and lower the energy for methanol-oriented photoproduction route. Finally, the  $MoS_xSe_yN_z$  has improved the photoproduction of methanol reduced from  $CO_2$  by 162%.

#### 1. Introduction

The industrial development in the last decades has consumed a huge amount of fossil fuels, resulting in the emission of several billion tons of carbon dioxide that cause the intensive greenhouse effect and other environmental problems [1]. Thus, the capture and recycling of CO<sub>2</sub> has become an urgent demand for sustaining development [2]. Photocatalytic CO<sub>2</sub> reduction, combining the usage of solar energy and recycling of CO2 to small organic fuel molecules, is widely considered as a promising solution to the above issue [3]. Since 1979, Inoue et al.[4] first reported photo-induced carbon dioxide reduction with TiO2. Tremendous works have been done to continuously explore new semiconductors for photocatalytic CO<sub>2</sub> reduction such as metal oxides (TiO<sub>2</sub>, WO<sub>3</sub>, ZnO, etc.) [5-8], metal sulfide of CdS [9], Ag- and Bi-based photocatalysts (Ag<sub>3</sub>PO<sub>4</sub>, Bi<sub>2</sub>MoO<sub>6</sub>, etc.) [10,11]. Generally, the photocatalytic CO<sub>2</sub> reduction has to overcome two main challenges to realize industrial application. One is to achieve highly efficient conversion in the visible windows [12]. The other is to achieve high selectivity in the production, which requires a precise design on the photocarrier transport. The variety of valence states of carbon could involve up to eight electrons during the reduction of  ${\rm CO_2}$ , which is sensitively influenced by the energy level alignment on the active site of the photocatalyst. Thus, photocatalysts with a finely tunable band structure would be perfect for that purpose.

The semiconducting two-dimensional (2D) materials such as transition metal dichalcogenides (TMDs) have been regarded as a very promising photocatalyst for  $CO_2$  reduction due to the visible absorption and continuously tunable band edge [13], while multivariate elements can further enlarge the tunable ranges of band structure[14]. For example, the ternary  $MoS_xSe_y$  had exhibited a tunable band gap between 1.64 eV and 1.82 eV [15]. Additionally, the atomic thickness of 2D materials has shorten the photocarrier diffusion distance and thus enhanced the carrier transport [16].

However, the TMDs still have to overcome some challenges before qualified for practical photocatalytic CO<sub>2</sub> reduction [12]. The strong intrinsic recombination in a single phased TMDs still inhibits the

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effective electron transport for photocatalytic CO<sub>2</sub> reduction. A typical solution to intrinsic recombination is to employ the dual-excitation Z-type heterojunction to facilitate the separation of photocarriers [17]. Nevertheless, there is a side effect of heterojunction, which is that the different nature of materials on the two sides would result in unbalanced carriers in the interface. The unbalanced carriers would not transport along the Z-scheme path, which is possible to transfer directly to CO<sub>2</sub> to trigger a side reaction [18]. In a multivariate TMDs material, such as the ternary MoS<sub>x</sub>Se<sub>v</sub>, the electronegativity among the non-metallic elements could be slightly different i.e. 2.58 for that of S and 2.55 for that of Se, which might give a directional force to induce the carrier transport. However, the difference in electronegativity between S and Se is not big enough to form a strong built-in electric field to favor the separation of photocarriers [19,20]. When excited by light, due to the high scattering probability [21], the photogenerated electrons in the d-orbital of Mo atom have very close chance to transfer either to S or Se position, which cannot form a directed transport and thus the severe recombination still exits. Under this consideration, this work has introduced nitrogen as the third non-metallic element into the ternary MoS<sub>x</sub>Se<sub>v</sub> lattice to form the quarternary TMDs of MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub>. The electronegativity of N is 3.04, which is much higher than that of S or Se. Therefore, the dipole of N-S and N-Se is more polarized than that of S-Se, which might induce the gathering of electrons around the N sites i.e. the separation of photocarriers might be favored. Thus, the built-in electric field formed via the photogenerated electron-hole pairs would be strengthened, which would be probably favor a directed carrier transport of the photocarriers inside the material and inhibit the recombination. The enhanced built-in electric field has also promoted the gathering of electrons around N sites. which has been found to improve the adsorption of intermediate products and lower the energy for methanol-oriented photoproduction route. The built-in electric field featured MoSxSevNz as a single phased photocatalyst has improved the photoproduction of methanol by 162% compared to MoS<sub>x</sub>Se<sub>v</sub>. Meanwhile, the quantum selectivity of methanol production has been also increased by 13% accordingly.

#### 2. Experimental section

# 2.1. Chemicals

Molybdenum trioxide (MoO<sub>3</sub>, Aladdin, 99.5%), selenium powder (Se, Aladdin, 99.99%), sulfur powder (S, Sinopharm Chemical Reagent Co., Ltd (China), > 99.0%), NaHCO<sub>3</sub>, (Xilong Chemical Co. Ltd (China), > 99.5%).

#### 3. Synthesis of photocatalysts

## 3.1. MoS<sub>x</sub>Se<sub>y</sub> synthesis

The  $MoS_xSe_y$  was synthesized on the surface of quartz glass via Chemical Vapor Deposition (CVD) method in a tube furnace with double temperature zones. Sulfur and selenium powders used as the source of S and Se were placed in the up-stream zone with the temperature of  $200\,^{\circ}$ C. The  $MoO_3$  powder was placed in the down-stream zone with the temperature of  $750\,^{\circ}$ C, while the quartz glass sheets were placed down-stream. A mixed gas flow of  $100\,^{\circ}$  sccm  $H_2$  and  $400\,^{\circ}$  sccm Ar was introduced as the reacting and carrying-protecting gas respectively. The deposition was set to  $1\,^{\circ}$ h while the pressure was kept at  $200\,^{\circ}$ Pa.

# 3.2. $MoS_xSe_yN_z$ synthesis

Under the normal pressure, the synthesized quartz glass  $MoS_xSe_y$  material was placed at the central zone of the tube furnace under the temperature of 750 °C with the heating rate of 5 °C per minute, where the mixed gas flow of 30 sccm  $NH_3$  and 200sccm Ar was introduced as the reacting and carrying-protecting gas, respectively. The temperature was kept for one hour and the furnace was cooled down to room

temperature naturally.

#### 4. Characterization

The morphology and structure were characterized by via scanning electron microscopy (SEM, Carl Zeiss Supra 55), high-resolution transmission electron microscopy (HRTEM, JEOL2100), X-ray diffraction (XRD, Rigaku Ultima IV) and X-ray Photoelectron Spectroscopy (XPS, Quantum 2000). The optical properties were studied using UV-Vis absorption spectrometer (Shimadzu UV-2600), photoluminescence (PL, Hitachi F-7000) and Raman spectrometer (excitated by 532 nm diodepumped solid-state laser). The photoelectrochemical measurements including Mott-Schottky measurement, photocurrent and electrochemical impedance spectra (EIS) were conducted by electrochemical workstation equipped with three electrode system (Shanghai Chenhua Instrument Co., LTD CHI660E). Atomic force microscopy (AFM, Cypher S, Asylum) equipped with Ti/Ir coated silicon tip (Asyelec 01-R2) was employed to trace the surface smoothness (tapping mode) as well as the corresponding potential distribution (scanning Kelvin probe microscopy).

#### 5. Photoelectrochemical measurements

The Quartz glass- $MoS_xSe_y$  and  $MoS_xSe_yN_z$  electrodes were characterized in a three-electrode configuration using a Ag/AgCl reference electrode (in 3 M KCl aqueous solution) and a platinum sheet counter electrode.  $0.1\,M\,Na_2SO_4$  aqueous solution was used as electrode solution (pH 6.21). The potential of the working electrode was read from its current open-circuit voltage. The Mott-Schottky measurement was carried out with different frequency of 500 Hz and 1000 Hz, the calibration of potentials was referred to the reversible hydrogen electrode (RHE) according to Eq. (1) [22].

$$E (vs \cdot RHE) = E (vs Ag/AgCl) + 0.197 V + 0.0591 \times pH$$
 (1)

And the photoelectrode was irradiated with a solar simulator (AM  $1.5~G,\,300~W$ ) to do the photocurrent measurement with 100~s interval on-off for total 1100~s

#### 6. Photocatalytic CO<sub>2</sub> reduction

The photocatalytic CO $_2$  reduction was carried out under 0.2~Mpa CO $_2$  in a sealed autoclave at room temperature, and 0.1~M NaHCO $_3$  was used as the hydrogen source. An AM 1.5~G calibrated solar simulator (Sirius 300 P, 320–780 nm, 300 W, Zolix) equipped with a 420 nm longpass filter ( $\lambda \geq 420$  nm) was used as the light source. Gas chromatography (GC 9790) equipped with both gas and liquid analysis columns under flame ionization detector was used to detect gas phase and liquid phase products, respectively.

# 7. Results and discussion

The highly dense 2D  $MoS_xSe_y$  and  $MoS_xSe_yN_z$  nanosheets are found vertically standed and uniformly distributed on a 5 cm sized substrate, with the size around 2–4  $\mu$ m (Fig. 1a, d, S1 and S2), demonstrating the controllability and stability of the as-proposed synthesis which is suitable for mass production. The increased conductivity of the insulating substrate after growth of nanosheets (Fig. S2), has further proved the high density and uniformity of the nanosheets. HRTEM images shown in Figs. 1b and 1c have revealed that as-prepared  $MoS_xSe_y$  and  $MoS_xSe_yN_z$  nanosheets have the hexagonal lattice structure (2 H phase), while the stacking of (002) facets with the distance of  $\sim$ 0.637 nm can be identified (Fig. S3). Also, the (100) facets with d-spacing of  $\sim$ 0.275 nm can be observed. And the 2D structure of  $MoS_xSe_y$  nanosheets is from double-layered to multi-layered (Fig. S4), while 2–4 layers might be the main structure (Fig. S5). The inset of Fig. 1d and Fig. S5 verify the ultrathin 2D

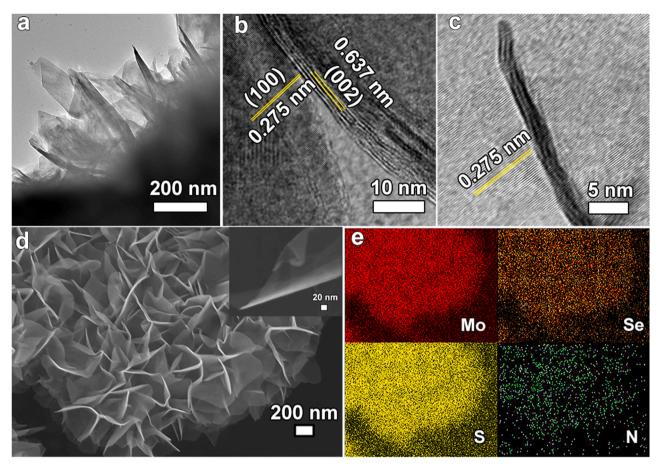


Fig. 1. (a) TEM and (b) HRTEM images of  $MoS_xSe_y$  nanosheets; (c) HRTEM and (d) SEM images of  $MoS_xSe_yN_z$  nanosheets; and (e) EDX elemental mapping of Mo (red), Se (brown), S (yellow) and N (green) in  $MoS_xSe_yN_z$ .

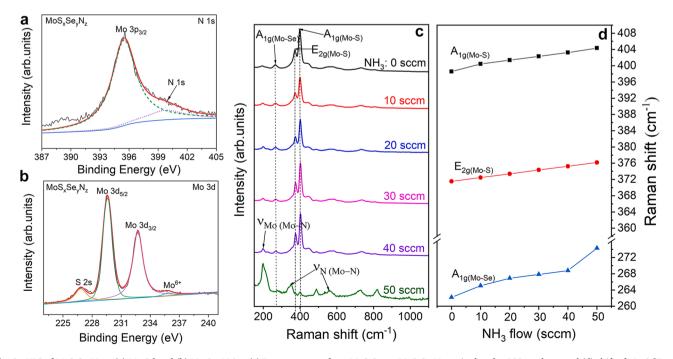


Fig. 2. XPS of  $MoS_xSe_yN_z$  at (a) Mo 3d and (b) Mo 3p, N 1 s; (c) Raman spectra from  $MoS_xSe_y$  to  $MoS_xSe_yN_z$  excited under 532 nm laser and (d) shift of Mo-S [E<sub>2 g(Mo-S)</sub>, A<sub>1 g(Mo-S)</sub>] and Mo-Se related modes [A<sub>1 g(Mo-Se)</sub>] with varying NH<sub>3</sub> flow rates.

structure of  $MoS_xSe_y$  nanosheets. Although the electronegativity of N is much higher than that of S or Se, the  $MoS_xSe_yN_z$  had maintained the original structure of  $MoS_xSe_y$ , indicating the introduction of N atoms and the corresponding bonding did not obviously change the lattice structure or form new phases. The energy dispersive X-ray (EDX) spectra shown in Table S1 has verified the presence of nitrogen in the structure of  $MoS_xSe_yN_z$ , while the elemental mapping for Mo, S, Se, and N shows that nitrogen had been uniformly and discretely added to the  $MoS_xSe_y$  nanosheets, as shown in Figs. 1d and 1e. By comparing the elements of  $MoS_xSe_y$  and  $MoS_xSe_yN_z$ , it can be concluded from Table S1 that the content of Se had been lowered with the presence of N.

The presence of nitrogen has been further traced by XPS and Raman spectra as shown in Fig. 2, S6 and S7. The Mo 3d signals in XPS (Fig. 2a) at  $\sim$ 229.6 and 232.7 eV corresponding to Mo  $3d_{5/2}$  and Mo  $3d_{3/2}$  could be observed in both  $MoS_xSe_y$  and  $MoS_xSe_yN_z$ , while  $MoS_xSe_yN_z$  exhibition ted another small peak at ~235.9 eV that was attributed to the existence fo  $Mo^{6+}$  [23,24]. Accordingly, the signal at ~399.9 eV near the  $\sim$ 395.5 eV of Mo 3p<sub>3/2</sub>, corresponding to N 1 s (Fig. 2b) could be also identified only in MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub>. The signal of Mo<sup>6+</sup> and N 1 s implies the Mo-N bonding in MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub>. On the other hand, the position of nitrogen in the lattice has been further studied by tracing the Raman shifts of MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub>, with continuously varying NH<sub>3</sub> flow rates (from 0 to 50 sccm) used in the fabrication. As shown in Figs. 2c and 2d, the typical modes [15,25] of Mo-S [ $A_{1 \text{ g(Mo-S)}}$ ,  $E_{2 \text{ g(Mo-S)}}$ ] are found to be fading out gradually with the increase of nitrogen. Similarly, the Mo-Se  $[A_{1 \text{ g(Mo-Se)}}]$ mode [15,25] has also exhibited the same trend. The mode at 197.8 cm<sup>-1</sup> might be attributed to the Mo vibration of Mo-N bonding and the corresponding N vibration is observed at 354.9 cm<sup>-1</sup> and 557.2 cm<sup>-1</sup> [26–28], while the intensity of those are found to be strengthened with continuous increase of NH3 flow rates. It should be also noticed that the Mo-S and Mo-Se related modes blue-shifted with the increase of nitrogen, as shown in Fig. 2d. The  $A_{1~g(Mo\text{-}S)}$  mode shifted from 398.6 cm $^{-1}$  to 404.3 cm $^{-1}$ , and the  $E_{2~g(Mo\text{-}S)}$  shifted from 371.5 cm $^{-1}$  to 376.6 cm $^{-1}$ . More obviously, the mode of  $A_{1~g(Mo\text{-}Se)}$  shifted from 262.2 cm $^{-1}$  to 274.3 cm $^{-1}$ . As mentioned above, the HRTEM and XRD results suggest that the hexagonal structure has been maintained in  $MoS_xSe_yN_z$  i.e. there was no new phase forming during the introduction of nitrogen. It can be deduced that nitrogen has been successfully inserted into the lattice of  $MoS_xSe_y$  and probably settled down in the non-metal positions.

The MoS<sub>x</sub>Se<sub>v</sub> has exhibited two TMDs based typical absorption peaks at 615 nm and 675 nm, respectively, while those of the MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> have shifted to 610 nm and 670 nm, as shown in Fig. 3a. Correspondingly, the band gap of MoS<sub>x</sub>Se<sub>v</sub> and MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> extracted from absorption spectra based on Tauc's relation is 1.50 eV and 1.60 eV, respectively (Fig. S8a), indicating that the additional nitrogen might slightly broaden the band gap because of the strong electronegativity of nitrogen in Mo-N bonding. The broadening of band gap from MoS<sub>x</sub>Se<sub>v</sub> to MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> can be further verified by  $E_g = E_{CBM} - E_{VBM}$ , while  $E_{CBM}$  is the conduction band minimum (CBM) measured by Mott-Schottky method [29], and  $E_{VBM}$  is the valence band maximum (VBM) extracted from valence band XPS (Fig. S8). It shows that the CBM is -1.34 eV (-0.73 eV vs. RHE) for  $MoS_vSe_v$ , and -1.42 eV (-0.81 eV vs. RHE) for  $MoS_vSe_vN_z$ . Meanwhile, the VBM is 0.75 eV for MoS<sub>x</sub>Se<sub>v</sub>, and 0.80 eV for MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub>. Therefore, the band gap deduced from CBM and VBM would be 1.48 eV and 1.61 eV, respectively, in consistence with the Tauc's relation derived band gaps. To further investigate the evolution of electronic structure from a ternary MoS<sub>x</sub>Se<sub>v</sub> to the quarternary MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub>, density Functional Theory (DFT) calculation was employed to analyze the band structure of  $MoS_xSe_v$  (x, y = 0-2) with part of non-metal positions replaced by N atoms, as shown in Fig. S9. The Vienna Ab Initio Simulation Package (VASP) with the projector-augmented wave (PAW)

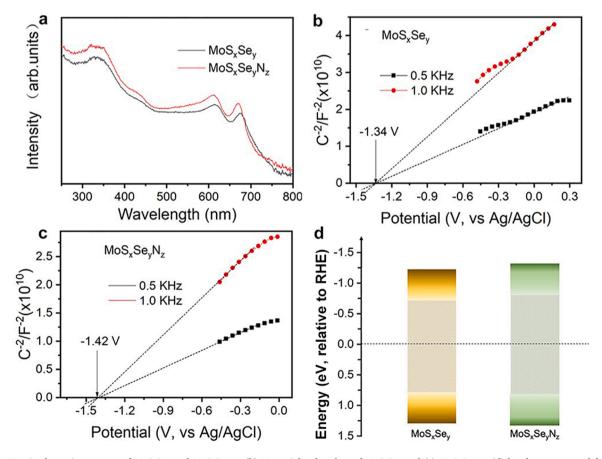


Fig. 3. (a) UV-vis absorption spectra of  $MoS_xSe_yN_z$ , (b) Mott-Schottky plots of  $MoS_xSe_y$  and (c)  $MoS_xSe_yN_z$ , (d) band gap extracted from UV-vis absorption spectra based on Tauc's relation, and checked via CBM extracted from (b), (c) and VBM extracted from valance band XPS in Fig. S8.

method was used for all DFT calculations[30,31]. The generalized gradient approximation (GGA) with Perdew-Burke-Ernzerhof (PBE) algorithm[32] was selected to describe the exchange-correlation functional. The long-range van der Waals force has been considered in calculations by DFT-D3 approach[33]. The vacuum layers are larger than 15 Å in structure models to restrain the interaction between adjacent layers. The Monkhorst-Pack k-mesh grid was sampled with  $9 \times 9 \times 1$  for unit cell calculations. The energy cut-off, convergence criteria for the electronic and ionic relaxation steps are 400 eV,  $1\times10^{-4}\,$ eV/cell and 0.05 eV/Å, respectively to ensure the calculation accuracy. The results show that in the case of two-layered TMDs MoS<sub>2</sub> and MoSe<sub>2</sub>, the band gap has been found enlarged with presence of 1.39% N (Fig. S10). Consequently, according to the evolution of band structure from MoS<sub>x</sub>Se<sub>y</sub> to MoS<sub>x</sub>Se<sub>y</sub>N<sub>z</sub> as shown in Fig. 3d, it should be noticed that with the band gap broadending of MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub>, the CBM has been also raised up a bit, from which an enhanced reduction potential can be predicted reasonably.

Furthermore, the DFT calculation carried in different S/Se ratio of  $MoS_xSe_y$  structure (Fig. S9) also shows that with a proper percentage of N in the lattice, the band gap of  $MoS_xSe_yN_z$  will be slightly enlarged and the CBM will be lowered a bit (Fig. S10). More importantly, the DFT calculation has predicted that due to the difference in electronegativity of S, Se and N, the nitrogen induced dipole moment and potential energy will be greater. Once part of chalcogens replaced by N atoms in  $MoS_xSe_y$ , known as  $MoS_xSe_yN_z$ , the nitrogen induced intrinsic dipoles of N-S and N-Se will be much stronger than that of S-Se, hopefully to facilitate the separation of photocarriers. By comparing the intrinsic dipoles in Janus-structured MoSSe, MoSN and MoSeN using DFT, it is found that the dipole moment in different sites change with the pairs based on different

elements, i.e. of N-Se  $(0.061 \text{ e} \cdot \text{Å}) > \text{N-S} (0.040 \text{ e} \cdot \text{Å}) > \text{S-Se} (0.036 \text{ e} \cdot \text{Å})$ , as shown in Fig. S11. Correspondingly, the evolution of potential energy has been also found increased from MoSSe to MoSN and MoSeN. Furthermore, the DFT calculation for a uniform MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> shown in Fig. 4a has also revealed that the dipole induced difference in the potential energy  $\Delta V$  has been enhanced at N-Se pair (1.28 eV) with the dipole moment pointing from Se to N (Fig. 4b). Based on the nonuniform potential distribution in MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> as shown in Fig. 4c, the potential  $\Delta V$  in N-Se pair is theoretically predicted to be the highest. Correspondingly, the nitrogen induced potential difference could be also traced via the AFM working in Kelvin probe microscopy mode [34], as shown in Fig. 5. MoS<sub>x</sub>Se<sub>v</sub> had exhibited an indistinguishable potential distribution. On the opposite, the potential distribution of MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> had obviously shown a non-uniform trace. Since the Kelvin probe microscopy was taken in a constant-distance mode, the potential distribution should be uniform as long as the dipole moments along the material was uniform regardless of the surface roughness, which is the case of MoS<sub>x</sub>Se<sub>v</sub>. Once there is a discretely distributed element with obviously different electronegativity, such as nitrogen, the dipole moments at those regions will be different and then result in a non-uniform potential distribution as the theoretical analysis suggested. The non-uniform potential distribution implies localized gathering of electrons, which is most likely to occur around the N sites as described in Fig. 4d, could be favorable for the CO2 adsorption and production of high value added products reduced from CO<sub>2</sub>.

In addition, the photoluminescence (PL) of  $MoS_xSe_yN_z$  was quenched compared to that of  $MoS_xSe_y$ , while the luminescence lifetime [35] had been prolonged from 2.90 ns to 4.05 ns, as shown in Fig. 6a and b, implying that the intrinsic recombination of photocarriers was not that

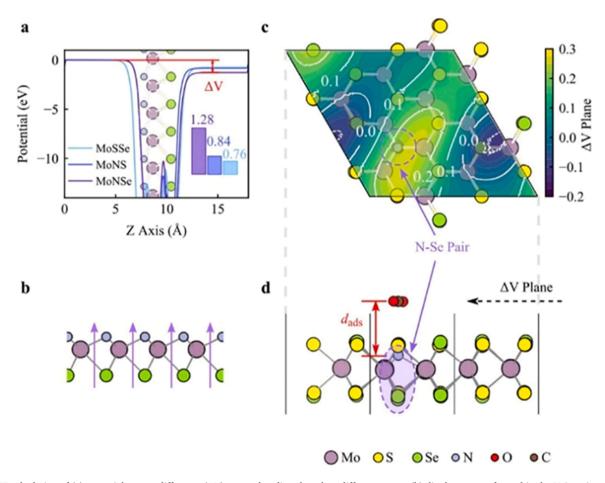


Fig. 4. DFT calculation of (a) potential energy difference ( $\Delta V$ ) among bondings based on different atoms; (b) dipole moment formed in the N-Se pair structure; (c) distribution of potential energy difference ( $\Delta V$ ) in MoS<sub>x</sub>Se<sub>y</sub>N<sub>z</sub> structure projected along z-axis and (d) adsorption of CO<sub>2</sub> at N site of MoS<sub>x</sub>Se<sub>y</sub>N<sub>z</sub> structure.

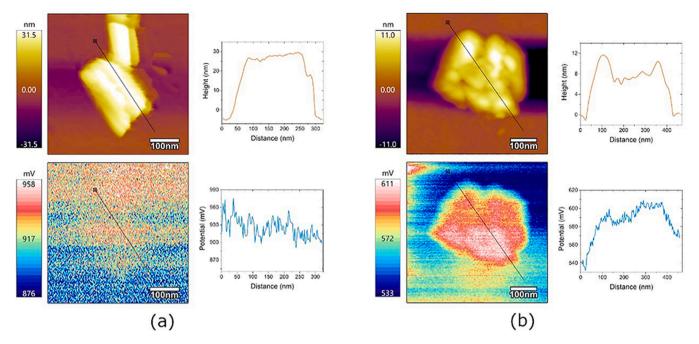


Fig. 5. Height (upper) and potential (lower) traces in AFM of (a)  $MoS_xSe_y$  and (b)  $MoS_xSe_yN_z$ . The linear change in height and potential along the labelled line starting from the square mark are shown in the spectrum type as well.

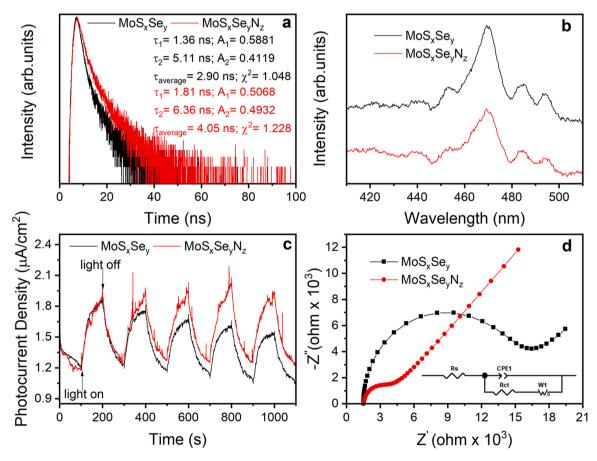


Fig. 6. (a) Time-resolved PL; (b) PL spectra; (c) photocurrent responses and (d) EIS of MoS<sub>x</sub>Se<sub>y</sub> and MoS<sub>x</sub>Se<sub>y</sub>N<sub>z</sub>.

significant in  $MoS_xSe_yN_z$  compared to  $MoS_xSe_y$ , and the photocarrier transport in  $MoS_xSe_yN_z$  could be profited from that. The enlarged difference in electronegativity has made the intrinsic dipole moments between N and chalcogens i.e. N-S and N-Se dipole much stronger than that

formed among chalcogens (S-Se), which means the bonding electrons are closer to N atoms. Also, with the presence of Mo-N bonding, the N atoms would be in the form of  $N^3$ , which means each N atom needs one more electron than S or Se to form stable bonding with Mo. In that case,

there would be more holes around the N sites to maintain the electric neutrality. Therefore, the discrete enhanced built-in electric fields pointing from N regions to non-N regions could form, inducing a directed photocarrier transport to favor the separation of photocarriers. The enhanced photocarrier transport and built-in electric field might also lead to an increased photocurrent [36]. As shown in Fig. 6c, the average on/off photocurrent density of  $MoS_xSe_vN_z$  is about 0.7  $\mu$ A/cm<sup>2</sup>, which is a bit larger than that of  $0.51 \,\mu\text{A/cm}^2$  in  $\text{MoS}_x\text{Se}_v$ . Meanwhile, EIS was also employed to study the surface/interface reaction kinetics and the nature of resistances, as shown in Fig. 6d. [37-39]. The Nyquist plot of MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> has exhibited a smaller semicircle than that of  $MoS_xSe_v$ , from which the charge-transfer resistance ( $R_{ct}$ ) of  $MoS_xSe_vN_z$ and MoS<sub>x</sub>Se<sub>v</sub> were extracted to be 3.8 K $\Omega$  and 15.6 K $\Omega$ , respectively. The relatively smaller R<sub>ct</sub> on the surface of MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> might also imply a favored photocarrier transport, which might be corresponding to the enhanced built-in electronic field induced N-S and N-Se dipoles, facilitating a directed photocarrier transport. Generally, with a higher CBM i. e. enhanced reducing capability and facilitated photocarrier transport, MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> could be predicted to perform better on photocatalytic CO<sub>2</sub> reduction.

Fig. 7 and S12 show the performance of  $MoS_xSe_y$  and  $MoS_xSe_yN_z$  on photocatalytic  $CO_2$  reduction. The presence of a carbon-fixed product of  $CH_3OH$  could be observed, with two additional gases i.e. CO and  $CH_4$  had been also detected. Both  $MoS_xSe_y$  and  $MoS_xSe_yN_z$  have revealed a long-term stability of photocatalytic  $CO_2$  reduction under visible irradiation, while  $MoS_xSe_yN_z$  obtained in 30 sccm  $NH_3$  has the best performance among  $MoS_xSe_yN_z$ . The electrons for  $CO_2$  reduction to different carbon products showing as the following formulas [40]:

$$CO_2 + 2e^- + 2 H^+ \to CO + H_2O$$
 (2)

$$CO_2 + 6e^- + 6 H^+ \rightarrow CH_3OH + H_2O$$
 (3)

$$CO_2 + 8e^- + 8 H^+ \rightarrow CH_4 + 2 H_2O$$
 (4)

It is clear that 6 electrons are needed for the generation of each CH<sub>3</sub>OH molecule (Eq. (3)), while only 2 electrons are required by CO production (Eq. (2)) and 8 for CH<sub>4</sub> (Eq. (4)). For MoS<sub>x</sub>Se<sub>y</sub>, the production rate of CH<sub>3</sub>OH is  $1.79~\mu$ mol g<sup>-1</sup>h<sup>-1</sup>, while the production rates of CO and

 $CH_4$  are 3.21  $\mu$ mol g<sup>-1</sup>h<sup>-1</sup> and 0.27  $\mu$ mol g<sup>-1</sup>h<sup>-1</sup>, respectively. Quantum selectivity for CH<sub>3</sub>OH production calculated via (Eqn. S1) is 56%. For  $MoS_xSe_vN_z$ , the production rate of CH<sub>3</sub>OH has been improved by  $\sim 162\%$ to 4.69  $\mu$ mol g<sup>-1</sup>h<sup>-1</sup>, nearly three times over that of MoS<sub>x</sub>Se<sub>v</sub>. The production of CO has been obviously weakened, and production of CH<sub>4</sub> has been increased a bit to 1.31 µmol g<sup>-1</sup>h<sup>-1</sup>. Quantum selectivity for  $\mbox{CH}_{3}\mbox{OH}$  production in  $\mbox{MoS}_{x}\mbox{Se}_{y}\mbox{N}_{z}$  has been increased to 69%. The production rate of CH<sub>3</sub>OH has been increased by about three times and the corresponding selectivity has been increased by 13% with the presence of nitrogen. The optimized production rate and quantum selectivity for CH<sub>3</sub>OH in the single phased MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> has demonstrated the positive effect on the photocatalytic performance, with the presence of nonmetallic elements beyond the chalcogens i.e. nitrogen. The presence of nitrogen in MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> induced intrinsic dipoles of N-S and N-Se have been found stronger than that of S-Se, which could enhance the localized built-in electric fields pointing from N regions to non-N regions i.e. photogenerated electrons would be more likely to move toward and gather around N sites. Thus, the high concentration of photogenerated electrons around the N sites has made them very active for the reduction of CO<sub>2</sub>, where the electrons might preferably transfer to CO<sub>2</sub> trigger the production of high value added products. On the opposite site, the excited holes also gathered beyond N sites under the enhanced built-in electric field to complete the oxidation courses. In a word, the built-in electric field enhanced by strong electronegativity of nitrogen has favored the separation and transport of photocarriers to improve the photocatalytic performance. Meanwhile, it should be noticed that the production rates of both CH<sub>3</sub>OH and CH<sub>4</sub> in MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> has been improved, while that of CO was weakened. Since production of CO requires only 2 electrons, which is the most straightforward production of reducing CO<sub>2</sub>, the decrease of CO production rate would also imply that the presence of nitrogen in the lattice might be also favorable for the capture of CO<sub>2</sub> and intermediate product [41], inducing further electron transferring and the forming of complicated products.

To elucidate the specific role of nitrogen in the electron transport for photocatalytic CH<sub>3</sub>OH production in details, the adsorption of intermediate products around different elements among the surface of  $MoS_xSe_vN_z$  had been further studied via DFT calculation. At the

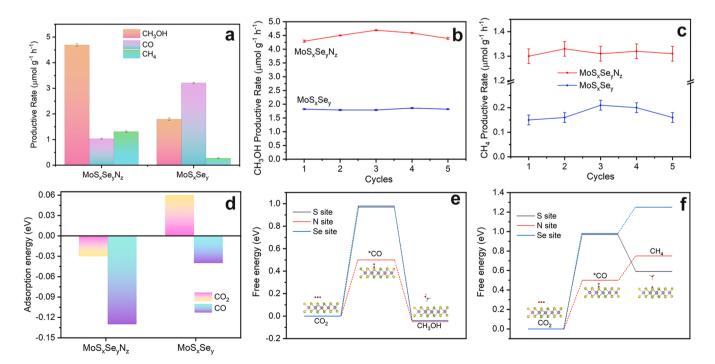


Fig. 7. (a) The Photocatalytic CO<sub>2</sub> reduction productivity of MoS<sub>x</sub>Se<sub>y</sub> and MoS<sub>x</sub>Se<sub>y</sub>Nz; stability of (b) CH<sub>3</sub>OH production and (c) CH<sub>4</sub> production; (d) DFT calculation of adsorption energy of CO<sub>2</sub> and CO; (e) free energy of CH<sub>3</sub>OH route and (f) CH<sub>4</sub> route at S, N and Se sites.

beginning of a complete photocatalytic CO<sub>2</sub> reduction process, photocarriers are generated and separated while the catalyst excited by light, and CO2 molecules are adsorbed on the surface of the catalyst [40]. It has been found in Fig. 7d that the adsorption energy  $\Delta E_{ad}$  of CO<sub>2</sub> on the N sites is negative i.e exothermic rather than positive i.e. endothermic on the chalcogen sites, indicating a more stable adsorption of CO2 on the N sites. Once the electrons transfer to CO2, CO2 begins to be reduced through two potential routes that are competing with each other: fast hydrogenation (FH) and fast deoxidization (FdO, known as the carbene mechanism) [42]. Since CH<sub>3</sub>OH and CH<sub>4</sub> were both observed in the products, the as-proposed MoS<sub>x</sub>Se<sub>v</sub> and MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> would be more likely to follow a carbene-dominant route. Firstly, the adsorbed CO2 is reduced to \*COOH and then reduced to \*CO, as shown in Fig. S13 (CH<sub>3</sub>OH route) and S14 (CH<sub>4</sub> route) [43]. The calculated free energy has revealed this step needs much less energy at N sites than that at either S or Se sites, indicating that the CO<sub>2</sub> reduction will be more likely to start at N site. The DFT calculation has also shown a more stable adsorption of CO at the N sites (Fig. 7d), which is favorable for the following reaction. On the other hand, the relatively weaker absorption of CO on MoS<sub>x</sub>Se<sub>v</sub> surface might cause the desorption of CO and thus lower the chance of the following reaction. Besides, the DFT calculation has also predicted that the further reaction for converting \*CO to the next intermediate products would be also more straightforward to occur at N sites rather than S or Se sites due to the advantage of low energy need for the reaction at N sites, in both CH<sub>3</sub>OH route (Fig. S13) and CH<sub>4</sub> route (Fig. S14). Therefore, CO is the main product on the MoS<sub>x</sub>Se<sub>v</sub>, while MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> would have a higher chance to conduct the following reactions, which has been verified by the obvisouly weakened photocatalytic CO production of MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> compared to MoS<sub>x</sub>Se<sub>v</sub>. Meanwhile, as mentioned before, the dipole of N-Se and N-S would result in the gathering of electrons around N site to trigger multi-electrons invovled production like CH<sub>4</sub> and CH<sub>3</sub>OH. Since the electrons required for CH<sub>3</sub>OH production (6 electrons) are a few less than that for CH<sub>4</sub> production (8 electrons), the production of CH<sub>3</sub>OH might be more straightforward. Accordingly, Fig. 7e and S13 have shown that around N site the CH<sub>3</sub>OH route could occur spontaneously due to the decrease on energy from \*CO to CH<sub>3</sub>OH. However, for the CH<sub>4</sub> route, more extra energy and electrons are needed for the following reaction (Fig. 7f and S14). It has been also shown (Fig. S15) that the adsorption energy of CH<sub>3</sub>OH is low, indicating a higher chance for the desorption of CH<sub>3</sub>OH to stop the potential following reaction.

Therefore, the production rate of  $CH_3OH$  has been found to be obviously higher than that of  $CH_4$  on both  $MoS_xSe_y$  and  $MoS_xSe_yN_z$ . Generally, at the essential step of  $CO_2$  to \*CO, which requires extra energy, the N-Se dipole enhanced built-in electric field has provided abundant electrons on the surface of  $MoS_xSe_yN_z$  that also has a stronger adsorption of \*CO to conduct the following reactions. As a result, the productivity and selectivity of  $CH_3OH$  have been enhanced in  $MoS_xSe_yN_z$  compared to  $MoS_xSe_y$ .

The original mechanism in the band structure of the enhancement of photocatalytic performance from MoS<sub>x</sub>Se<sub>v</sub> to MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> is discussed. As commonly known, the strong recombination of photocarriers in a single phased photocatalyst hinders the gathering of photogenerated electrons and their transport from photocatalyst to CO2, resulting in a relatively low production rate. The intrinsic built-in electric field is not strong enough to realize efficient separation of photocarriers. The weak gathering of photogenerated electrons cannot provide CO2 sufficient electrons for a multi-step reduction to obtain high value added products, which makes the photocatalytic product from a single phased photocatalyst is usually dominated by CO that only induces two electrons, as shown in Table S2. The ternary elemental design of MoS<sub>x</sub>Se<sub>v</sub> actualizes the precise band alignment for selective production of photocatalytic CO<sub>2</sub> reduction, yet the difference in electronegativity between S ane Se is not significant enough to hinder recombination and form strong builtin electric field, providing sufficient electrons to facilitate a multi-step photoreduction of CO2. In that case, CO is still the main product from MoS<sub>v</sub>Se<sub>v</sub>. On the contrary, a quarternary MoS<sub>v</sub>Se<sub>v</sub>N<sub>z</sub> with the presence of a non-chalcogen element, nitrogen, would have a different band structure. The strong electronegativity of nitrogen helps to form strong builtin electric fields and gather the photogenerated electrons around, has demonstrated a CH<sub>3</sub>OH dominant production in the photocatalytic CO<sub>2</sub> reduction. It should be noticed that according to the EDX results the content of nitrogen in MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> was just a little, and the photocurrent of MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> was just a bit higher than that of MoS<sub>x</sub>Se<sub>v</sub> as well. However, the production rate of CH<sub>3</sub>OH of MoS<sub>x</sub>Se<sub>v</sub>N<sub>z</sub> has been significantly increased, indicating that the improvement should not be mainly attributed to an increased photocarrier concentration, but was due to a more effective and directed transport, as well as a more straightforward CH<sub>3</sub>OH oriented reaction route, with the presence of nitrogen. It can be concluded that the electronegative diversity between chalcogens and nitrogen induced strong dipole moments has effectively facilitated the gathering and transport of photogenerated electrons to trigger the high value added production.

#### 8. Conclusion

 $MoS_xSe_yN_z$  nanosheets has been synthesized for photocatalytic  $CO_2$  reduction. The difference in electronegativity among the non-metal elements has been used to form strong dipoles to favor the separation of photocarriers and thus enhance the built-in electric field. Therefore, the gathering of photogenerated electrons around N sites has improved the multi-electron involved photoreduction from  $CO_2$  to  $CH_3OH$  by 162%.

# CRediT authorship contribution statement

Deng Long: Conceptualization, Methodology, Validation, Formal analysis, Investigation, Writing – original draft, Visualization. Jia Liu: Software, Formal analysis. Hongyu Chen: Validation, Formal analysis. Pei Liu: Formal analysis. Kai Zheng: Formal analysis. Yibo Zeng: Formal analysis. Xinyi Chen: Conceptualization, Methodology, Investigation, Resources, Writing – review & editing. Supervision, Project administration, Funding acquisition. Shuang Li: Software, Formal analysis, Resources. Miao Lu: Resources, Supervision, Funding acquisition.

#### **Declaration of Competing Interest**

The authors declare that they have no known competing financial interests or personal relationships that could have appeared to influence the work reported in this paper.

#### **Data Availability**

Data will be made available on request.

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#### Appendix A. Supporting information

Supplementary data associated with this article can be found in the online version at <a href="doi:10.1016/j.apcatb.2023.122625">doi:10.1016/j.apcatb.2023.122625</a>.

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